

ISL9016

150mA Dual LDO with Low Noise, High PSRR, and Low I<sub>Q</sub>

FN6832  
Rev 1.00  
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ISL9016 is a high performance dual LDO capable of providing up to 150mA current on each channel. It features a low standby current and very high PSRR and is stable with output capacitance of 1μF to 4.7μF with an ESR of up to 200mΩ.

The device integrates a separate enable function for each output. The quiescent current is typically 49μA when only one LDO is enabled and typically 80μA when both LDOs are enabled. When both LDOs are under shutdown condition, the drawing current is typically less than 1μA.

ISL9016 provides a wide input voltage range from 1.8V to 6.5V. It also has a high PSRR of 80dB at 1kHz and 45dB at 1MHz. ISL9016 also provides output current limit, overheat protection, reverse current protection, as well as excellent load transient response.

ISL9016 is offered in a tiny 1.6mmx1.6mm 6 Ld μTDFN package. Output voltage options are available from 1.2V to 3.3V. Several combinations of voltage outputs are standard and others may be available upon request.

Features

- Dual Integrated 150mA High Performance LDOs
- High PSRR: 80dB @ 1kHz and 45dB @ 1MHz
- Reverse Current Protection
- Low Quiescent Current
  - 49μA (Single LDO Enabled)/80μA (Dual LDOs Enabled)
- Excellent Load Transient Response
- Typically ±0.8% Output Voltage Accuracy
- Low Output Noise: Typically 25μV<sub>RMS</sub>
- Wide Input Voltage Capability: 1.8V to 6.5V
- Low Dropout Voltage: Typically 120mV @ 150mA
- Separate Enable Control for each LDO
- Stable with 1μF to 4.7μF Ceramic Output Capacitors
- Soft-start to Limit Input Current Surge During Enable
- Current Limit and Overheat Protection
- Tiny 6 Ld 1.6mmx1.6mm μTDFN package
- Pb-free (RoHS Compliant)

Applications

- PDAs, Cell Phones and Smart Phones
- Portable Instruments, MP3/4 Players, PMP, DSC
- Handheld Devices including Medical Handhelds

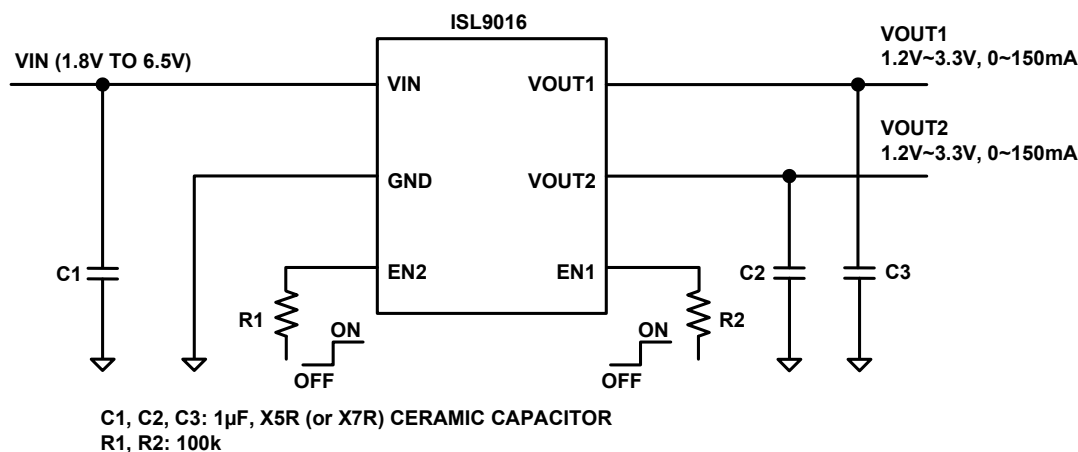
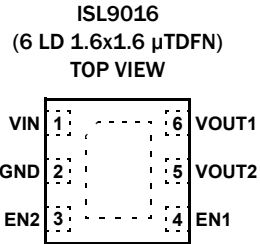


FIGURE 1. TYPICAL APPLICATION DIAGRAM

## Pin Configuration



## Pin Descriptions

PIN #	PIN NAME	DESCRIPTION
1	VIN	Supply Voltage/LDO Input. Connect a 1 $\mu$ F capacitor to GND.
2	GND	GND is the connection to system ground. Connect to PCB Ground plane.
3	EN2	LDO2 Enable pin. Enable = High, Disable = Low. A 100k resistor should be connected between EN2 and the control voltage rail. Do NOT leave it floating.
4	EN1	LDO1 Enable pin. Enable = High, Disable = Low. A 100k resistor should be connected between EN1 and the control voltage rail. Do NOT leave it floating.
5	VOUT2	LDO2 Output. Connect capacitor with a value from 1 $\mu$ F to 4.7 $\mu$ F to GND (1 $\mu$ F recommended).
6	VOUT1	LDO1 Output. Connect capacitor with a value from 1 $\mu$ F to 4.7 $\mu$ F to GND (1 $\mu$ F recommended).
-	E-Pad	Connect the e-pad to the system ground.

## Ordering Information

PART NUMBER (Notes 1, 3)	PART MARKING	VO1 VOLTAGE (V) (Note 2)	VO2 VOLTAGE (V) (Note 2)	TEMP RANGE (°C)	PACKAGE (Pb-Free)	PKG DWG. #
ISL9016IRUWCZ-T	N7	1.2	1.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUWGZ-T	N6	1.2	2.7	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUWJZ-T	N2	1.2	2.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUWKZ-T	N1	1.2	2.85	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUBWZ-T	R7	1.5	1.2	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUBBZ-T	R6	1.5	1.5	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUCWZ-T	R5	1.8	1.2	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUCBZ-T	R4	1.8	1.5	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUCCZ-T	U7	1.8	1.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUFWZ-T	R3	2.5	1.2	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUFBZ-T	N8	2.5	1.5	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUFCZ-T	N9	2.5	1.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUFFZ-T	P0	2.5	2.5	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUGWZ-T	P1	2.7	1.2	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUGCZ-T	R2	2.7	1.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUGGZ-T	N3	2.7	2.7	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUJWZ-T	P2	2.8	1.2	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUJBZ-T	P3	2.8	1.5	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUJCZ-T	N4	2.8	1.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUJJZ-T	N0	2.8	2.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUKWZ-T	P5	2.85	1.2	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUKFZ-T	P4	2.85	2.5	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUKKZ-T	N5	2.85	2.85	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUMWZ-T	P6	3.0	1.2	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUMBZ-T	P7	3.0	1.5	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUMCZ-T	P8	3.0	1.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUMKZ-T	P9	3.0	2.85	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUNWZ-T	R0	3.3	1.2	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A
ISL9016IRUNCZ-T	R1	3.3	1.8	-40 to +85	6 Ld µTDFN	L6.1.6x1.6A

## NOTES:

1. Please refer to [TB347](#) for details on reel specifications.
2. For other output voltages, contact Intersil marketing or local sales office.
3. These Intersil Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and Tin Bismuth plate - e6 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
4. For Moisture Sensitivity Level (MSL), please see device information page for [ISL9016](#). For more information on MSL please see techbrief [TB363](#).

**Absolute Maximum Ratings**

$V_{IN}$ to GND	-0.3V to +7.1V
All Other Pins to GND	-0.3 to ( $V_{IN} + 0.3$ )V

**Recommended Operating Conditions**

Supply Voltage ( $V_{IN}$ )	1.8V to 6.5V
Each LDO Load Current	up to 150mA
Ambient Temperature Range ( $T_A$ )	-40 °C to +85 °C

**Thermal Information**

Thermal Resistance	$\theta_{JA}$ (°C/W)
6 Ld $\mu$ TDFN Package (Note 5)	117.5
Junction Temperature Range	-40 °C to +125 °C
Operating Temperature Range	-40 °C to +85 °C
Storage Temperature Range	-65 °C to +150 °C
Pb-Free Reflow Profile	see link below <a href="http://www.intersil.com/pbfree/Pb-FreeReflow.asp">http://www.intersil.com/pbfree/Pb-FreeReflow.asp</a>

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

**NOTE:**

- $\theta_{JA}$  is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.

**Electrical Specifications** Typical specifications are measured at the following conditions:  $T_A = +25$  °C;  $V_{IN} = (V_O + 0.5V)$  to 6.5V with a minimum  $V_{IN}$  of 1.8V;  $C_{IN} = 1\mu F$ ;  $C_O = 1\mu F$ . **Boldface limits apply over the operating temperature range, -40 °C to +85 °C.**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNITS
<b>DC CHARACTERISTICS</b>						
Supply Voltage	$V_{IN}$		<b>1.8</b>		<b>6.5</b>	V
UVLO Threshold	$V_{UV+}$			1.710	<b>1.775</b>	V
	$V_{UV-}$		<b>1.55</b>	1.62		
Input Quiescent Current		Quiescent condition: $I_{O1} = 0\mu A$ ; $I_{O2} = 0\mu A$				
	$I_{DD1}$	One LDO active		49	<b>67</b>	$\mu A$
	$I_{DD2}$	Both LDO active		80	<b>100</b>	$\mu A$
Shutdown Current	$I_{DSD}$	@ +25 °C		0.1	1.0	$\mu A$
Regulation Voltage Accuracy		$V_{IN} = V_O + 0.5V$ to 6.5V, $I_O = 10\mu A$ to 150mA, $T_A = +25$ °C	-0.8		+0.8	%
		$V_{IN} = V_O + 0.5V$ to 6.5V, $I_O = 10\mu A$ to 150mA, $T_A = -40$ °C to +85 °C	<b>-1.8</b>		<b>+1.8</b>	%
Maximum Output Current	$I_{MAX}$	Each LDO, Continuous	<b>150</b>			mA
Internal Current Limit	$I_{LIM}$		<b>175</b>	265	<b>355</b>	mA
Dropout Voltage (Note 6)	$V_{D01}$	$I_O = 150mA$ ; $1.2V \leq V_O \leq 2.1V$		250	<b>425</b>	mV
	$V_{D02}$	$I_O = 150mA$ ; $2.1V \leq V_O \leq 2.8V$		200	<b>325</b>	mV
	$V_{D03}$	$I_O = 150mA$ ; $2.8V \leq V_O$		120	<b>200</b>	mV
Thermal Shutdown Temperature	$T_{SD+}$			145		°C
	$T_{SD-}$			<b>110</b>		°C
<b>AC CHARACTERISTICS</b>						
Ripple Rejection		$I_O = 10mA$ , $V_{IN} = 3.7V(\text{min})$ , $V_O = 2.7V$ , $T_A = +25$ °C				
		@ 1kHz		80		dB
		@ 10kHz		60		dB
		@ 100kHz		50		dB
		@ 1MHz		45		dB
Output Noise Voltage		$V_{IN} = 4.2V$ , $I_O = 10mA$ , $T_A = +25$ °C, BW = 10Hz to 100kHz		25		$\mu V_{RMS}$
<b>DEVICE START-UP CHARACTERISTICS</b>						
Device Enable Time	$t_{EN}$	Time from assertion of the ENx pin to when the output voltage reaches 95% of the $V_O(\text{nom})$		400	<b>600</b>	$\mu s$
LDO Soft-Start Ramp Rate	$t_{SSR}$	Slope of linear portion of LDO output voltage ramp during start-up		30	<b>60</b>	$\mu s/V$

**Electrical Specifications** Typical specifications are measured at the following conditions:  $T_A = +25^\circ\text{C}$ ;  $V_{IN} = (V_O + 0.5\text{V})$  to 6.5V with a minimum  $V_{IN}$  of 1.8V;  $C_{IN} = 1\mu\text{F}$ ;  $C_O = 1\mu\text{F}$ . **Boldface limits apply over the operating temperature range,  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ . (Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNITS
<b>EN PIN CHARACTERISTICS</b>						
Input Low Voltage	$V_{IL}$	$T_A = -20^\circ\text{C}$ to $+85^\circ$	-0.3		0.4	V
Input High Voltage	$V_{IH}$		<b>1.1</b>		<b><math>V_{IN} + 0.3</math></b>	V
Input Leakage Current	$I_{IL}, I_{IH}$				<b>0.1</b>	$\mu\text{A}$
<b>REVERSE CURRENT CHARACTERISTICS</b>						
Output Reverse Leakage Current (Note 7)	$I_{ORLC}$	$V_{IN} = 0\text{V}, V_{OUT} = 5.5\text{V}$		8	<b>15</b>	$\mu\text{A}$

## NOTES:

- $V_{OX} = 0.98 * V_{OX}(\text{NOM})$ ; Valid for  $V_{OX}$  greater than 1.80V.
- Output reverse leakage current is measured with  $V_{IN}$  pin grounded and  $V_{OUT}$  pin connected to 5.5V.
- Parameters with MIN and/or MAX limits are 100% tested at  $+25^\circ\text{C}$ , unless otherwise specified. Temperature limits established by characterization and are not production tested.

## Typical Operating Performance

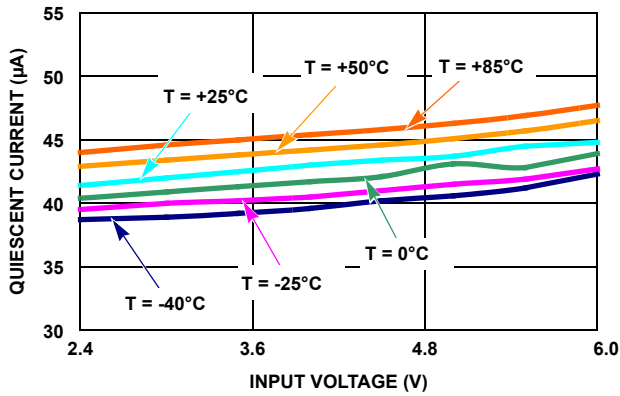


FIGURE 2. QUIESCENT CURRENT vs INPUT VOLTAGE ( $V_{OUT1} = 2.1V$ , ONLY LDO1 ENABLED)

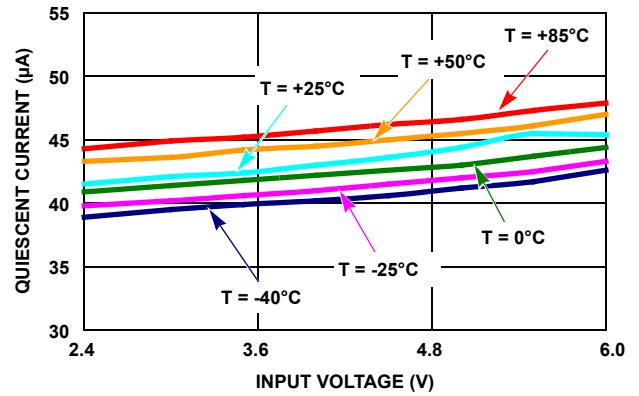


FIGURE 3. QUIESCENT CURRENT vs INPUT VOLTAGE ( $V_{OUT2} = 2.1V$ , ONLY LDO2 ENABLED)

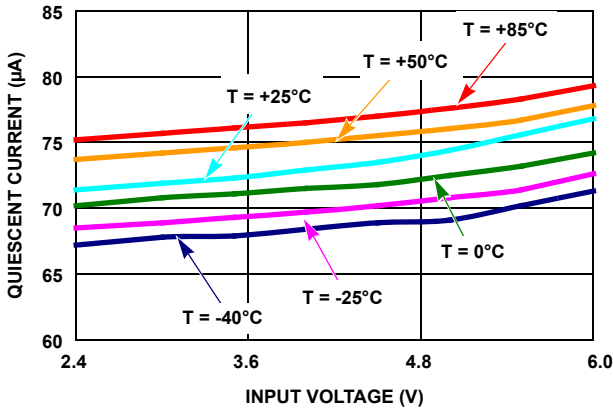


FIGURE 4. QUIESCENT CURRENT vs INPUT VOLTAGE ( $V_{OUT1} = V_{OUT2} = 2.1V$ , LDO1 AND LDO2 ENABLED)

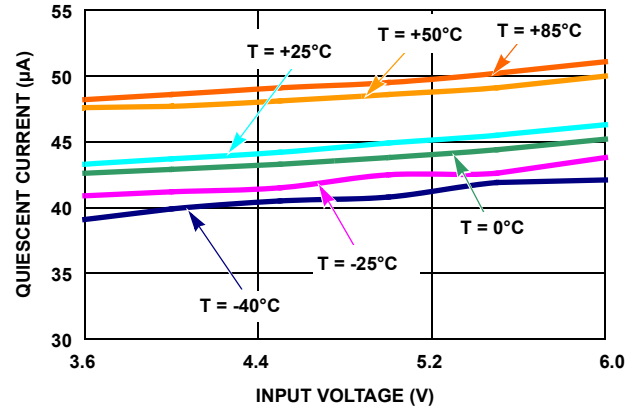


FIGURE 5. QUIESCENT CURRENT vs INPUT VOLTAGE ( $V_{OUT1} = 3.3V$ , ONLY LDO1 ENABLED)

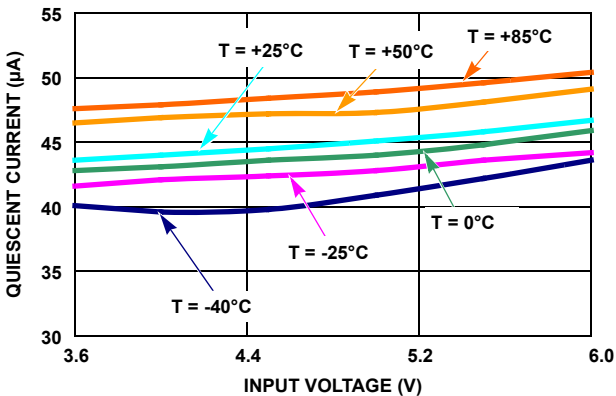


FIGURE 6. QUIESCENT CURRENT vs INPUT VOLTAGE ( $V_{OUT2} = 3.3V$ , ONLY LDO2 ENABLED)

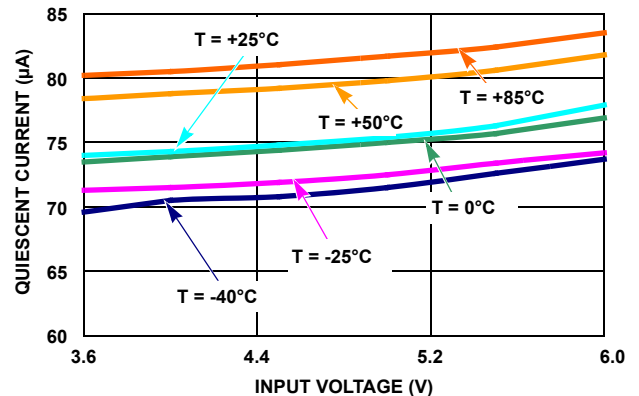


FIGURE 7. QUIESCENT CURRENT vs INPUT VOLTAGE ( $V_{OUT1} = V_{OUT2} = 3.3V$ , LDO1 AND LDO2 ENABLED)

## Typical Operating Performance (Continued)

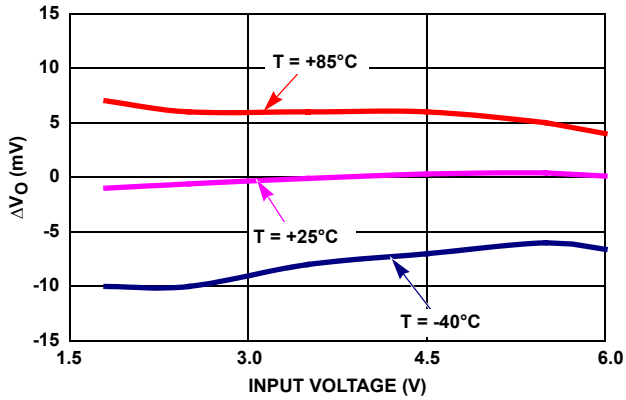


FIGURE 8.  $\Delta V_{OUT}$  vs INPUT VOLTAGE ( $V_{OUT\_NOMINAL} = 1.2V$ ,  $I_{OUT} = 50mA$ )

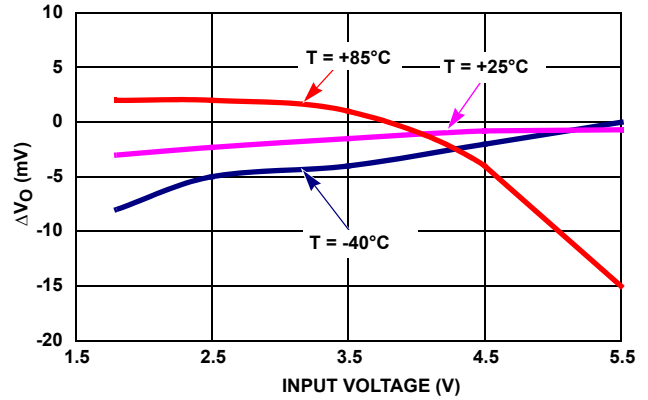


FIGURE 9.  $\Delta V_{OUT}$  vs INPUT VOLTAGE ( $V_{OUT\_NOMINAL} = 1.2V$ ,  $I_{OUT} = 150mA$ )

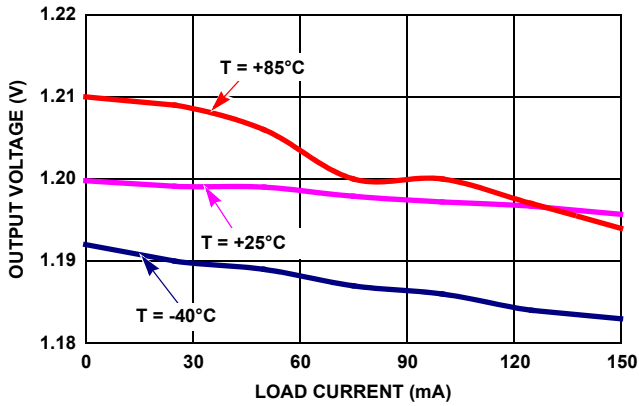


FIGURE 10. LOAD REGULATION ( $V_{IN} = 1.8V$ ,  $V_{OUT} = 1.2V$ )

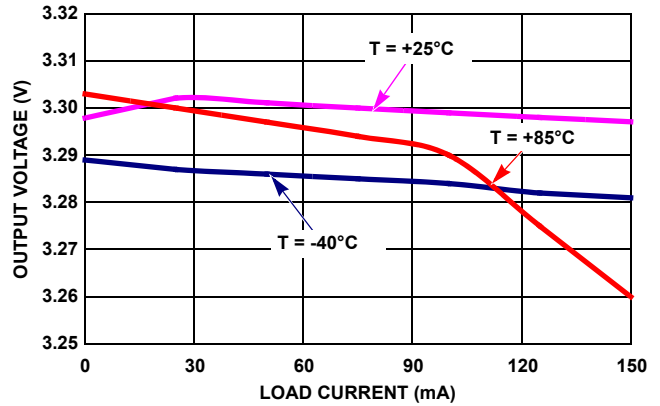


FIGURE 11. LOAD REGULATION ( $V_{IN} = 4.5V$ ,  $V_{OUT} = 3.3V$ )

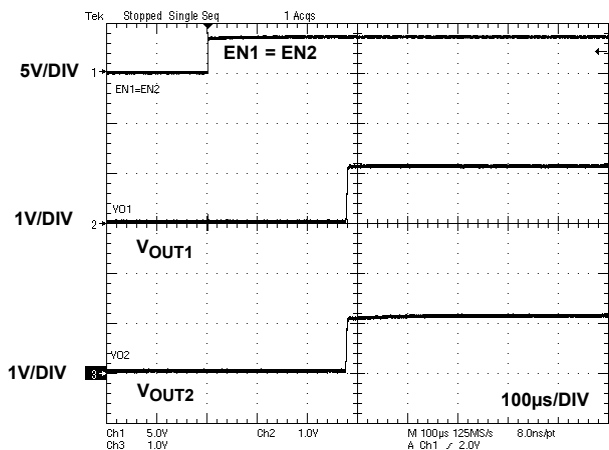


FIGURE 12. ENABLE OPERATION ( $V_{IN} = 3.6V$ ,  $V_{OUT1} = V_{OUT2} = 1.2V$ )

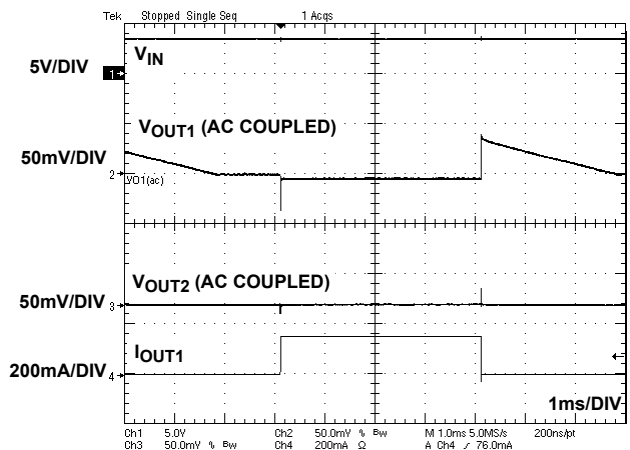
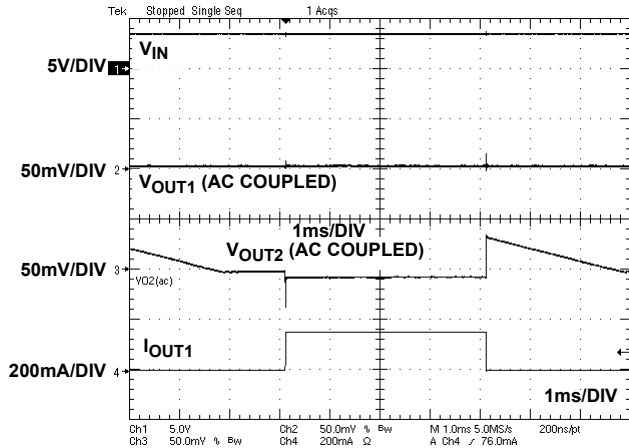
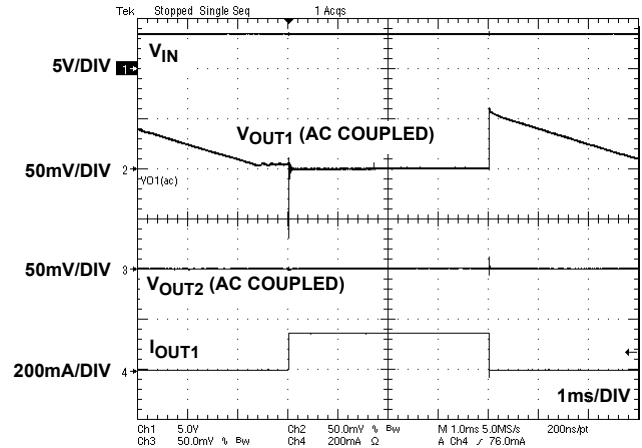


FIGURE 13. LOAD TRANSIENT RESPONSE ( $V_{IN} = 3.6V$ ,  $V_{OUT1} = V_{OUT2} = 1.2V$ ,  $I_{OUT1} 0.01mA$  TO  $150mA$ )

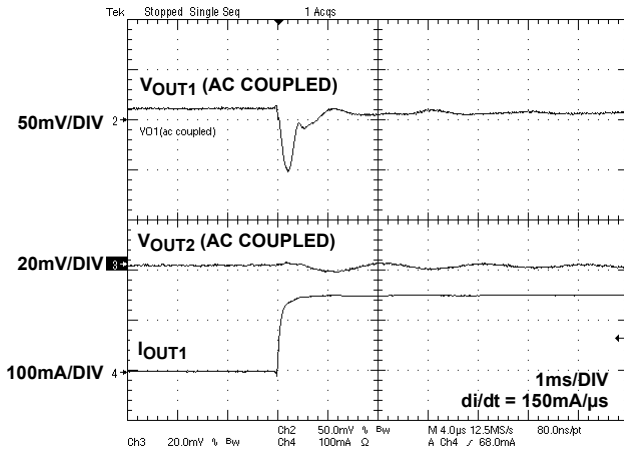
# Typical Operating Performance (Continued)



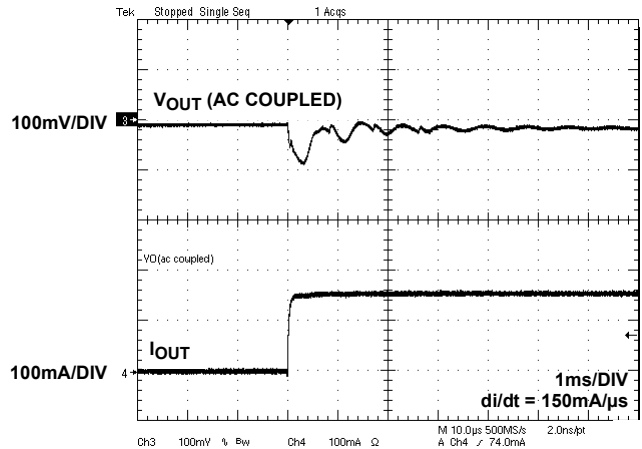
**FIGURE 14. LOAD TRANSIENT RESPONSE ( $V_{IN} = 3.6V$ ,  $V_{OUT1} = V_{OUT2} = 1.2V$ ,  $I_{OUT2} 0.01mA$  TO  $150mA$ )**



**FIGURE 15. LOAD TRANSIENT RESPONSE ( $V_{IN} = 3.6V$ ,  $V_{OUT1} = V_{OUT2} = 3.3V$ ,  $I_{OUT1} 0.01mA$  TO  $150mA$ )**



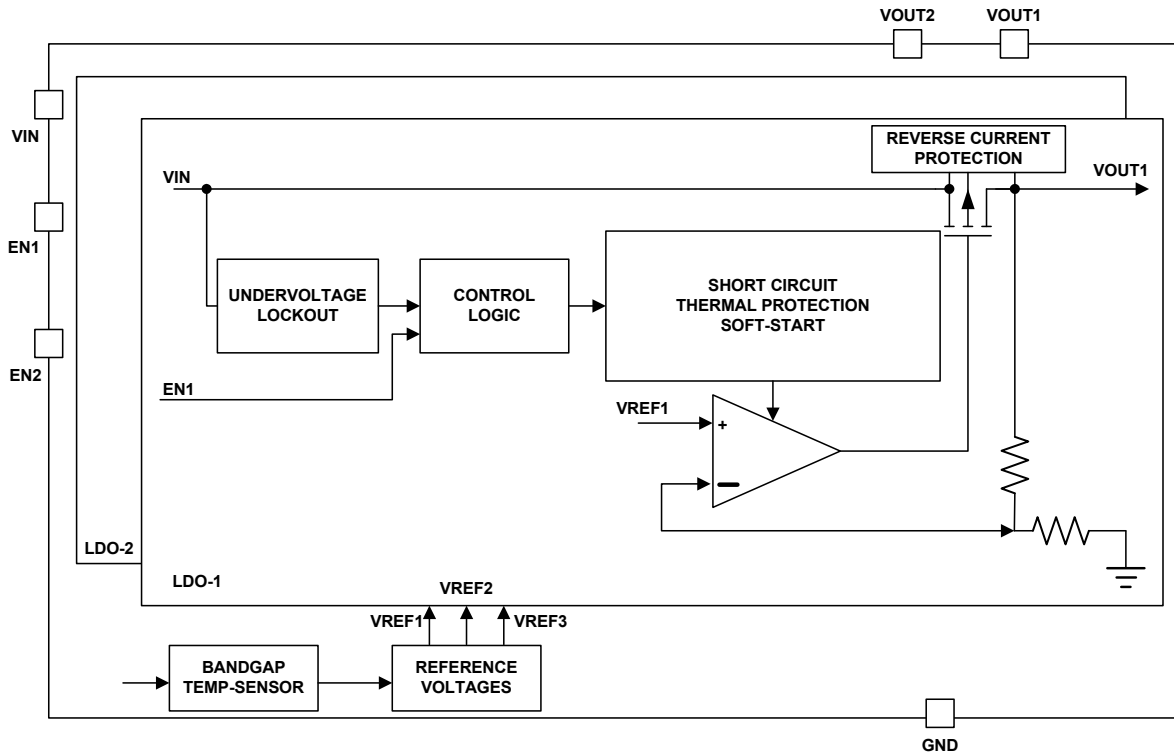
**FIGURE 16. LOAD TRANSIENT RESPONSE ( $V_{IN} = 1.8V$ ,  $V_{OUT1} = V_{OUT2} = 1.2V$ ,  $I_{OUT1} 0.01mA$  TO  $150mA$ )**



**FIGURE 17. LOAD TRANSIENT RESPONSE ( $V_{IN} = 3.3V$ ,  $V_{OUT1} = V_{OUT2} = 1.2V$ ,  $I_{OUT1} 0.01mA$  TO  $150mA$ )**



## Block Diagram



## Functional Description

ISL9016 contains two high performance LDO's. High performance is achieved through a circuit which delivers fast transient response to varying load conditions. In a quiescent condition, the ISL9016 adjusts its biasing to achieve the lowest standby current consumption.

The device also integrates current limit protection, thermal shutdown protection, reverse current protection and soft-start. Thermal shutdown protects the device against overheating. Soft-start limits the start-up input current surges. In some certain application circuits, the output voltage may be externally held up, meanwhile, the input voltage could be connected to ground, or connected to some voltage lower than the output side, or be left open circuit. ISL9016 features the reverse current protection; it can limit the current flow from output to input. This protection will automatically initiate when  $V_{OUT}$  is detected to be higher than  $V_{IN}$ . When  $V_{IN}$  is pulled to ground and  $V_{OUT}$  is held at 5.5V, the current flow from  $V_{OUT}$  to  $V_{IN}$  is typically less than  $8\mu\text{A}$ .

### Enable Control

The ISL9016 has two separate enable pins, EN1 and EN2, which independently enable/disable each of the LDO outputs. When both EN1 and EN2 are low, the whole device is in shutdown mode. In this condition, all on-chip circuits are off, and the device draws minimum current, typically less than  $0.1\text{mA}$ . When one or both the EN pins go high, the LDO1 and/or LDO2 will be enabled accordingly based on the voltage signal applied on its related EN pin and start from the soft-start. Likewise, when one or both EN pins go low, LDO1 and/or LDO2 will be disabled based on the signal applied on its related EN pin. A  $100\text{k}\Omega$  (or above) pull-up resistor should be connected

between ENx pin and the external control voltage (as shown in the "Typical Application Diagram" on page 1).

### LDO Protections

ISL9016 offers several protections which make it ideal for using in battery-powered application circuits.

ISL9016 provides short-circuit protection by limiting the output current to typical  $265\text{mA}$ . When short circuit happens, the circuit is limited at  $265\text{mA}$  (typical). If the short circuit lasts long enough, the die temperature increases, and the over-temperature protection circuit will turn off the output.

When the die temperature reaches about  $+145^\circ\text{C}$ , the thermal protection starts working. Under the overheat condition, only the LDO sourcing more than  $50\text{mA}$  will be shut off. This does not affect the operation of the other LDO. If both LDOs source more than  $50\text{mA}$  and an overheat condition occurs, both LDO outputs will be disabled. Once the die temperature falls back to about  $+110^\circ\text{C}$ , the disabled LDO(s) are re-enabled and soft-start automatically takes place.

In certain applications, the following input/output situations may occur, with output voltage externally held up higher than the input voltage:

1. Input is pulled to ground;
2. Input is left open circuit; and
3. Input is pulled to some intermediate voltage

ISL9016 provides the reverse current protection to limit the current flow from output to input under these situations. When input is pulled to ground and output is held to  $5.5\text{V}$ , the typical reverse current from output to input side is less than  $8\mu\text{A}$ .

## Input and Output Capacitors

The ISL9016 provides a linear regulator that has low quiescent current, fast transient response, and overall stability across the recommended operating conditions. A ceramic capacitor (X5R or X7R) with a capacitance of 1 $\mu$ F to 4.7 $\mu$ F with an ESR up to 200m $\Omega$  is suitable for the ISL9016 to maintain its output stability. The ground connection of the output capacitor should be connected directly to the GND pin of the device, and also placed close to the device. Similarly for the input capacitor, usually a 1 $\mu$ F ceramic capacitor (X5R or X7R) is suitable for most cases, but if large, fast rising-time load transient condition is expected, a higher value input capacitor may be necessary to achieve better performance.

## Board Layout Recommendations

A good PCB layout will be an important step to achieve good performance. It is recommended to design the board with separate ground planes for input and output, and connect both ground planes at the GND pin of the device. Consideration should be taken when placing the components and route the trace to minimize the ground impedance, as well as keep the parasitic inductance low. Usually the input/output capacitors should be placed close to the device with good ground connection.

## Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

DATE	REVISION	CHANGE
April 26, 2011	FN6832.1	Added ISL9016IRUCCZ-T to Ordering Information table.
January 22, 2009	FN6832.0	Initial release.

## Products

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\*For a complete listing of Applications, Related Documentation and Related Parts, please see the respective device information page on intersil.com: [ISL9016](http://www.intersil.com/ISL9016)

To report errors or suggestions for this datasheet, please go to: [www.intersil.com/askourstaff](http://www.intersil.com/askourstaff)

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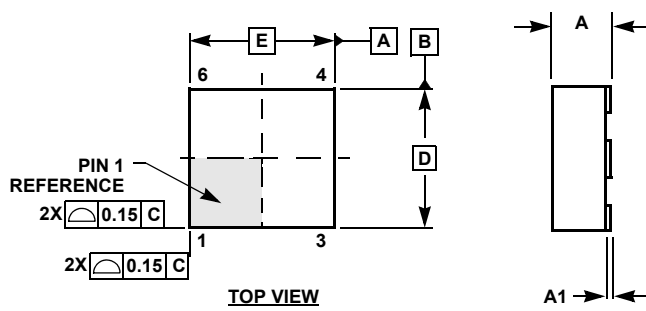
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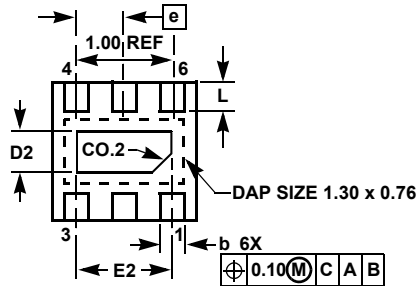
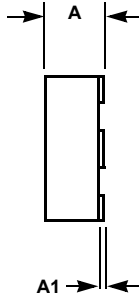
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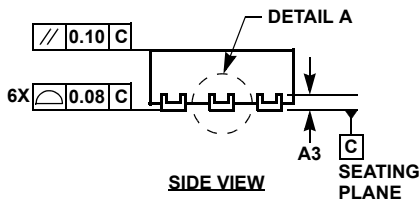
**Ultra Thin Dual Flat No-Lead Plastic Package (UTDFN)**



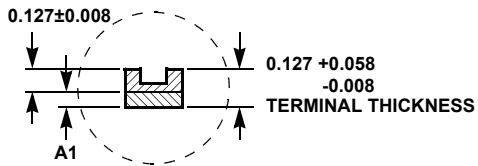
**TOP VIEW**



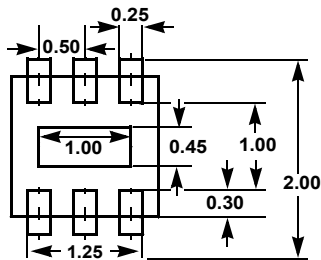
**BOTTOM VIEW**



**SIDE VIEW**



**DETAIL A**



**LAND PATTERN**

**L6.1.6x1.6A**

**6 LEAD ULTRA THIN DUAL FLAT NO-LEAD PLASTIC PACKAGE**

SYMBOL	MILLIMETERS			NOTES
	MIN	NOMINAL	MAX	
A	0.45	0.50	0.55	-
A1	-	-	0.05	-
A3	0.127 REF			-
b	0.15	0.20	0.25	-
D	1.55	1.60	1.65	4
D2	0.40	0.45	0.50	-
E	1.55	1.60	1.65	4
E2	0.95	1.00	1.05	-
e	0.50 BSC			-
L	0.25	0.30	0.35	-

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**NOTES:**

1. Dimensions are in mm. Angles in degrees.
2. Coplanarity applies to the exposed pad as well as the terminals. Coplanarity shall not exceed 0.08mm.
3. Warpage shall not exceed 0.10mm.
4. Package length/package width are considered as special characteristics.
5. JEDEC Reference MO-229.
6. For additional information, to assist with the PCB Land Pattern Design effort, see Intersil Technical Brief TB389.